

100V, 2 A NPN high power bipolar transistor 9 January 2014

Product data sheet

1. General description

NPN high power bipolar transistor in a SOT669 (LFPAK56) Surface-Mounted Device (SMD) power plastic package.

PNP complement: PHPT61002PYC

2. Features and benefits

- High thermal power dissipation capability
- High temperature applications up to 175 °C
- Reduced Printed Circuit Board (PCB) requirements comparing to transistors in DPAK
- High energy efficiency due to less heat generation

3. Applications

- Load switch
- Power management
- Linear mode voltage regulator
- Backlighting apllications

4. Quick reference data

Table 1. Quick reference data							
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V _{CEO}	collector-emitter voltage	open base		-	-	100	V
I _C	collector current			-	-	2	А
I _{CM}	peak collector current	single pulse; t _p ≤ 1 ms		-	-	6	А
R _{CEsat}	collector-emitter saturation resistance	I_C = 2 A; I_B = 200 mA; pulsed; t_p ≤ 300 μs; δ ≤ 0.02 ; T_{amb} = 25 °C		-	80	150	mΩ



100V, 2 A NPN high power bipolar transistor

5. Pinning information

Table 2.	Pinning	information		
Pin	Symbol	Description	Simplified outline	Graphic symbol
1	E	emitter	mb	C
2	E	emitter	LFPAK56; Power- SO8 (SOT669)	в-
3	E	emitter		
4	В	base		E sym123
mb	С	collector		Syll123

6. Ordering information

Table 3. Ordering information							
Type number	Package						
	Name	Description	Version				
PHPT61002NYC	LFPAK56; Power-SO8	Plastic single-ended surface-mounted package (LFPAK56; Power-SO8); 4 leads	SOT669				

7. Marking

Table 4. Marking codes	
Type number	Marking code
PHPT61002NYC	1002NCA

100V, 2 A NPN high power bipolar transistor

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

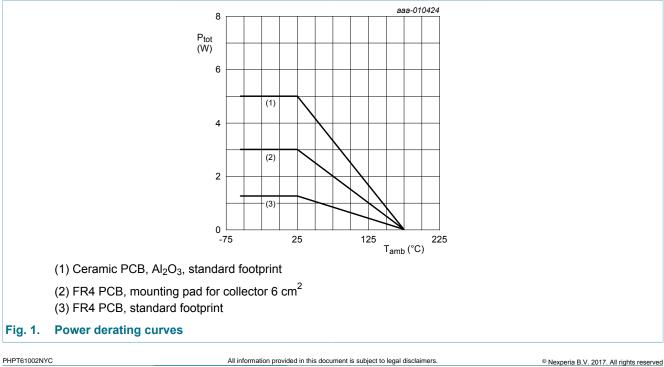
Symbol	Parameter	Conditions		Min	Мах	Unit
V _{CBO}	collector-base voltage	open emitter		-	100	V
V _{CEO}	collector-emitter voltage	open base		-	100	V
V _{EBO}	emitter-base voltage	open collector		-	7	V
I _C	collector current			-	2	А
I _{CM}	peak collector current	single pulse; t _p ≤ 1 ms		-	6	А
I _B	base current			-	0.5	А
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C	[1]	-	1.25	W
			[2]	-	3	W
			[3]	-	5	W
			[4]	-	25	W
Tj	junction temperature			-	175	°C
T _{amb}	ambient temperature			-55	175	°C
T _{stg}	storage temperature			-65	175	°C

[1] Device mounted on an FR4 Printed-Circuit Board (PCB); single-sided copper; tin-plated and standard footprint.

[2] Device mounted on an FR4 PCB; single-sided copper; tin-plated mounting pad for collector 6 cm².

[3] Device mounted on an ceramic PCB; AI_2O_3 ; standard footprint.

[4] Power dissipation from junction to mounting base.

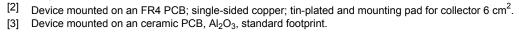


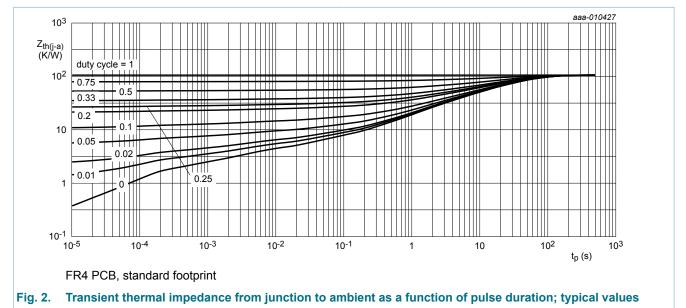
100V, 2 A NPN high power bipolar transistor

9. Thermal characteristics

Table 6. Thermal characteristics							
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
R _{th(j-a)}	thermal resistance from junction to ambient	in free air	[1]	-	-	115	K/W
			[2]	-	-	50	K/W
			[3]	-	-	30	K/W
R _{th(j-sp)}	thermal resistance from junction to solder point			-	-	6	K/W

[1] Device mounted on an FR4 Printed-Circuit Board (PCB); single-sided copper; tin-plated and standard footprint.

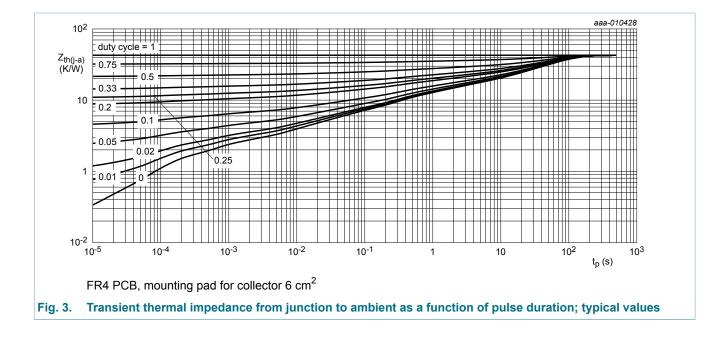




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100V, 2 A NPN high power bipolar transistor



100V, 2 A NPN high power bipolar transistor

10. Characteristics

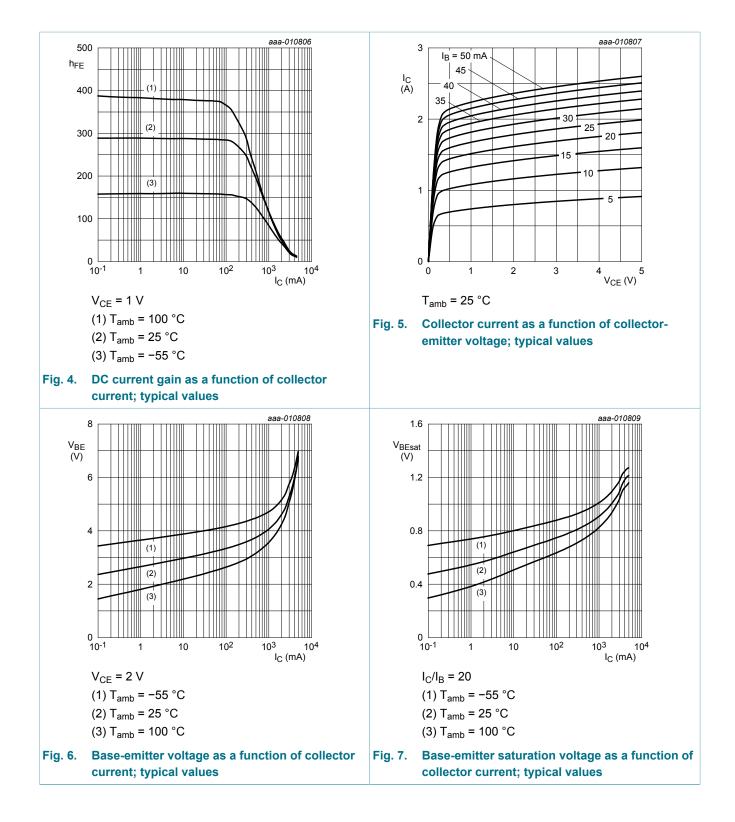
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
I _{CBO}	collector-base cut-off	V_{CB} = 80 V; I _E = 0 A; T _{amb} = 25 °C	-	-	100	nA
	current	V _{CB} = 80 V; I _E = 0 A; T _j = 150 °C	-	-	50	μA
I _{CES}	collector-emitter cut-off current	V_{CE} = 80 V; V_{BE} = 0 V; T_{amb} = 25 °C	-	-	100	nA
I _{EBO}	emitter-base cut-off current	V _{EB} = 7 V; I _C = 0 A; T _{amb} = 25 °C	-	-	100	nA
h _{FE}	DC current gain	V_{CE} = 1.5 V; I _C = 500 mA; T _{amb} = 25 °C	100	200	-	
		$\begin{split} V_{CE} &= 10 \text{ V}; \text{ I}_{C} = 500 \text{ mA}; t_{p} \leq 300 \mu\text{s}; \\ \delta \leq 0.02 ; T_{amb} = 25 ^{\circ}\text{C}; \text{ pulsed} \end{split}$	150	250	-	
		$\label{eq:VcE} \begin{split} V_{CE} &= 10 \text{ V}; \text{ I}_{C} = 1 \text{ A}; \text{t}_{p} \leq 300 \mu\text{s}; \\ \delta \leq 0.02 ; \text{T}_{amb} = 25 ^{\circ}\text{C}; \text{ pulsed} \end{split}$	80	200	-	
		$V_{CE} = 10 \text{ V}; \text{ I}_{C} = 2 \text{ A}; \text{ pulsed};$ $t_{p} \leq 300 \mu\text{s}; \delta \leq 0.02 ; \text{T}_{amb} = 25 ^{\circ}\text{C}$	20	140	-	
		$\label{eq:VCE} \begin{array}{l} V_{CE} \texttt{=} \ \texttt{10} \ V; \ I_{C} \texttt{=} \ \texttt{3} \ A; \ t_{p} \texttt{\leq} \texttt{300} \ \mu \texttt{s}; \\ \delta \texttt{\leq} \ \texttt{0.02} \ ; \ T_{amb} \texttt{=} \texttt{25} \ ^{\circ}C; \ \texttt{pulsed} \end{array}$	10	100	-	
V _{CEsat} coll	collector-emitter	I_{C} = 0.5 A; I_{B} = 50 mA; T_{amb} = 25 °C	-	50	75	mV
	saturation voltage	$I_{\rm C}$ = 2 A; $I_{\rm B}$ = 200 mA; pulsed;	-	160	300	mV
R _{CEsat}	collector-emitter saturation resistance	$t_p \le 300 \ \mu s; \ \delta \le 0.02; \ T_{amb} = 25 \ ^\circ C$	-	80	150	mΩ
V _{BEsat}	base-emitter saturation voltage	$\begin{split} &I_{C} = 1 \; A; \; I_{B} = 50 \; mA; \; pulsed; \\ &t_{p} \leq 300 \; \mus; \; \overline{o} \leq 0.02 \; ; \; T_{amb} = 25 \; ^{\circ}C \end{split}$	-	0.92	1	V
		$\begin{split} &I_{C}=\text{2 A; }I_{B}=\text{200 mA; pulsed;} \\ &t_{p}\leq\text{300 }\mu\text{s; }\delta\leq0.02\text{ ; }T_{amb}=\text{25 °C} \end{split}$	-	1.08	1.2	V
V _{BEon}	base-emitter turn-on voltage	V_{CE} = 2 V; I _C = 0.1 A; T _{amb} = 25 °C	-	0.68	0.85	V
t _d	delay time	V_{CC} = 12.5 V; I _C = 1 A; I _{Bon} = 0.05 A;	-	20	-	ns
t _r	rise time	I _{Boff} = -0.05 A; T _{amb} = 25 °C	-	300	-	ns
t _{on}	turn-on time		-	320	-	ns
t _s	storage time		-	830	-	ns
t _f	fall time		-	470	-	ns
t _{off}	turn-off time	-	-	1300	-	ns
f _T	transition frequency	V_{CE} = 10 V; I _C = 100 mA; f = 100 MHz; T _{amb} = 25 °C	-	140	-	MHz
C _c	collector capacitance	V _{CB} = 10 V; I _E = 0 A; i _e = 0 A; f = 1 MHz; T _{amb} = 25 °C	-	11	-	pF

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100V, 2 A NPN high power bipolar transistor



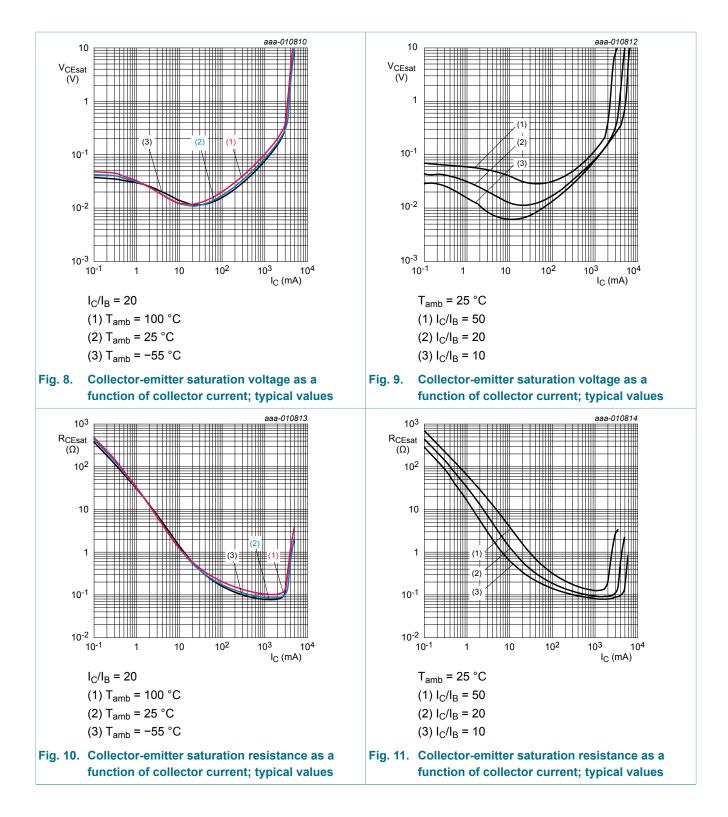
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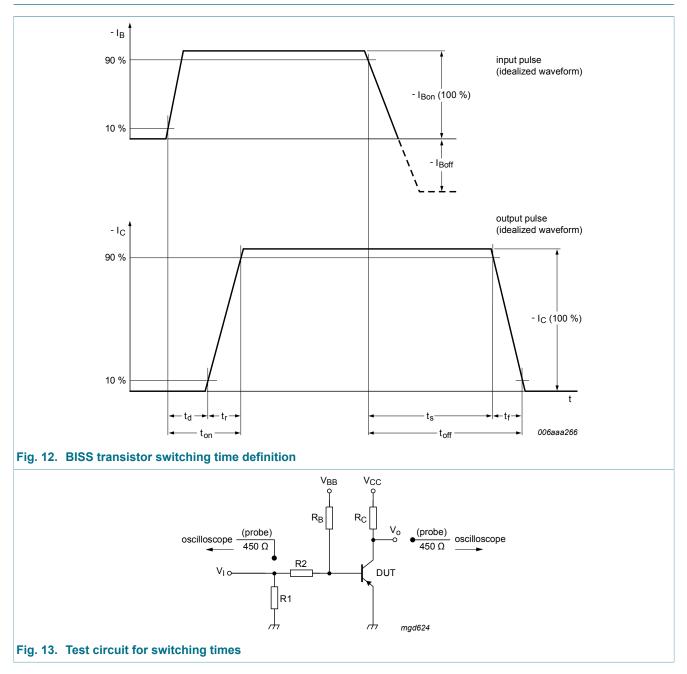
100V, 2 A NPN high power bipolar transistor



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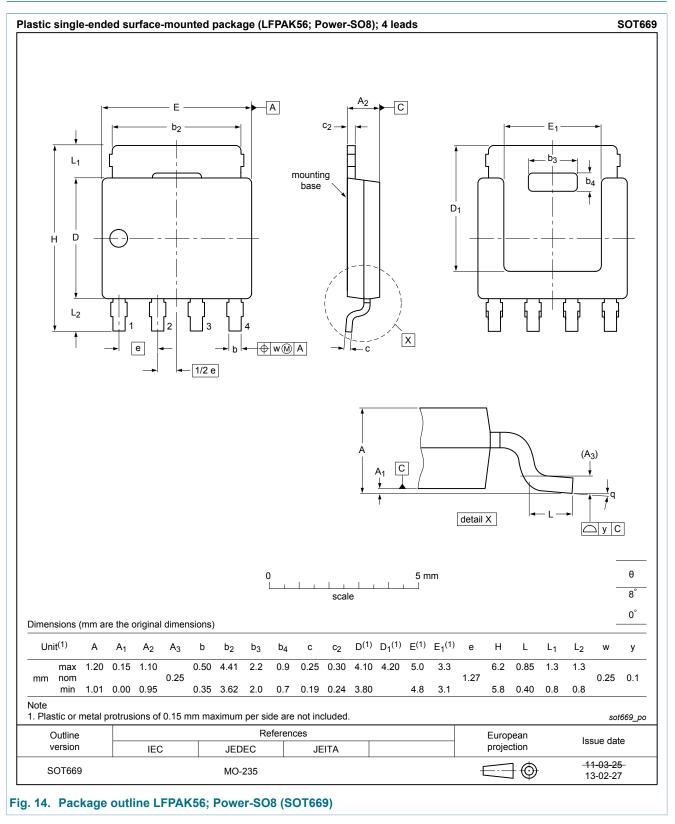
100V, 2 A NPN high power bipolar transistor



11. Test information

100V, 2 A NPN high power bipolar transistor

12. Package outline

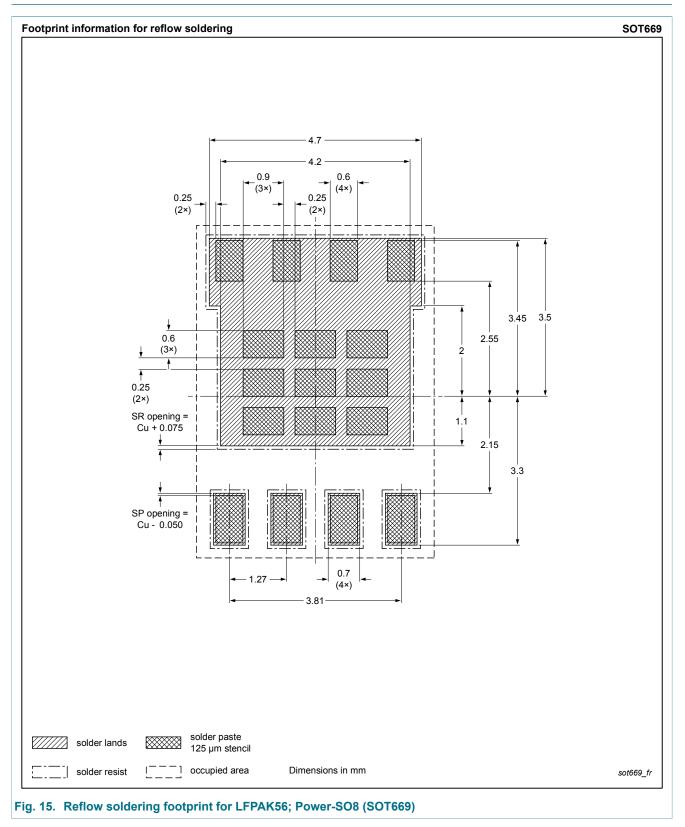


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100V, 2 A NPN high power bipolar transistor

13. Soldering



100V, 2 A NPN high power bipolar transistor

14. Revision history

Table 8. Revision his	Table 8. Revision history					
Data sheet ID	Release date	Data sheet status	Change notice	Supersedes		
PHPT61002NYC v.1	20140109	Product data sheet	-	-		

100V, 2 A NPN high power bipolar transistor

15. Legal information

15.1 Data sheet status

Document status [1][2]	Product status [<u>3]</u>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

 Please consult the most recently issued document before initiating or completing a design.

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